

TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRANSISTOR

TLP291(SE

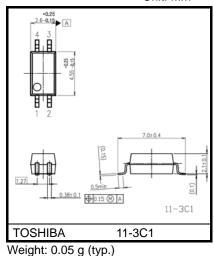
Power Supplies Programmable Controllers Hybrid ICs

TLP291(SE consists of photo transistor optically coupled to a gallium arsenide infrared emitting diode.

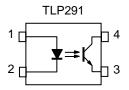
TLP291(SE is housed in the SO4 package, very small and thin coupler. Since TLP291(SE is guaranteed wide operating temperature (Ta=-55 to 110 °C) and high isolation voltage (3750Vrms), it's suitable for high-density surface mounting applications such as small switching power supplies and programmable controllers.

- Collector-Emitter Voltage : 80 V (min)
 - **Current Transfer Ratio** : 50% (min)
 - Rank GB : 100% (min)
 - **Isolation Voltage** : 3750 Vrms (min)
- Operation temperature: -55 to 110 °C
- UL recognized : UL1577, File No. E67349
- cUL approved
 - : CSA Component Acceptance Service No.5A, File No. E67349 : EN 60065: 2002,
- SEMKO conformity
- EN 60950-1: 2001, EN 60335-1: 2002,
- **BSI** conformity : BS EN 60065: 2002, BS EN 60950-1: 2006
- VDE conformity: EN 60747-5-5

Construction Mechanical Rating Creepage distance: 5.0mm(min) Clearance: 5.0mm(min) Insulation thickness: 0.4mm(min)



Pin Configuration



1:ANODE 2:CATHODE 3:EMITTER 4:COLLECTOR

Unit: mm

Current Transfer Ratio (CTR) Rank (Unless otherwise specified, Ta = 25°C)

TYPE	Classification	Current Trans (I _C	sfer Ratio (%) / I _F)			
	(Note1)	I _F = 5 mA, V _{CE} = 5 V, Ta = 25°C		Marking of Classification		
		Min	Max			
	Blank		600	Blank, YE, GR, GB, BL, Y+, G, G+,B		
	Rank Y	50	150	YE		
	Rank GR	100	300	GR		
	Rank GB	100	600	GB		
TLP291	Rank BL	200	600	BL		
	Rank YH	75	150	Y+		
	Rank GRL	100	200	G		
	Rank GRH	150	300	G+		
	Rank BLL	200	400	В		

Note1: Specify both the part number and a rank in this format when ordering

(e.g.) rank GB: TLP291 (GB,SE

For safety standard certification, however, specify the part number alone.

(e.g.)TLP291 (GB,SE: TLP291

			-		1
	CHARACTERISTIC	SYMBOL	NOTE	RATING	UNIT
	Input forward current	١ _F		50	mA
In	Input forward current derating (Ta≥90°C)	ΔI _F /ΔTa		-1.5	mA /°C
	Input forward current (pulsed)	I _{FP}	(Note 2)	1	А
LED	Input reverse voltage	ward current derating (Ta≥90°C) $\Delta I_F / \Delta Ta$ -ward current (pulsed) I_{FP} (Note 2)verse voltage V_R -wer dissipation P_D 1wer dissipation derating (Ta≥90°C) $\Delta P_D / \Delta Ta$ -temperature T_j 1r-emitter voltage V_{CEO} 6collector voltage V_{ECO} 6r current I_C 5r power dissipation derating(Ta≥25°C) $\Delta P_C / \Delta Ta$ -temperature T_j 1n perature T_j 1	5	V	
	Input power dissipation	PD		100	mW
	Input power dissipation derating (Ta \ge 90°C)	ΔΡ _D /ΔTa		-3.0	mW/°C
	Junction temperature	Тj		125	°C
	Collector-emitter voltage	V _{CEO}		80	V
æ	Emitter-collector voltage	V _{ECO}		7	V
DETECTOR	Collector current	Ι _C		50	mA
ETE	Junction temperature T_j 125Collector-emitter voltage V_{CEO} 80Emitter-collector voltage V_{ECO} 7Collector currentIc50Collector power dissipationPc150Collector power dissipation derating(Ta≥25°C) $\Delta P_C / \Delta Ta$ -1.5	150	mW		
ä	Collector power dissipation derating(Ta≥25°C)	ΔP _C /ΔTa		-1.5	mW /°C
	Junction temperature	Тj		125	°C
Ope	erating temperature range	T _{opr}		-55 to 110	°C
Stor	rage temperature range	T _{stg}		-55 to 125	°C
Lea	d soldering temperature	T _{sol}		260 (10s)	°C
Tota	al package power dissipation	Ρ _T		200	mW
Tota	al package power dissipation derating(Ta≥25°C)	ΔP _T /ΔTa		-2.0	mW /°C
Isol	ation voltage	BVS	(Note3)	3750	Vrms

Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25°C)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note2: Pulse width \leq 100 μ s, frequency 100Hz

Note3: AC, 1 minute, R.H.≤60%, Device considered a two terminal device: LED side pins shorted together and DETECTOR side pins shorted together.

Electrical Characteristics (Unless otherwise specified, Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
	Input forward voltage	VF	I _F = 10 mA	1.1	1.25	1.4	V
ΓED	Input reverse current	۱ _R	V _R = 5 V	-	-	5	μA
	Input capacitance	CT	V = 0 V, f = 1 MHz	-	30	-	pF
	Collector-emitter breakdown voltage	V _(BR) CEO	I _C = 0.5 mA	80	-	-	V
CTOR	Emitter-collector breakdown voltage	V _(BR) ECO	I _E = 0.1 mA	7	-	-	V
DETECT	Dark current	I _{DARK}	V _{CE} = 48 V	-	0.01	0.08	μA
			V _{CE} = 48 V, Ta = 85°C	-	2	50	μA
	Collector-emitter capacitance	C _{CE}	V = 0 V, f = 1 MHz	-	10	-	pF

Coupled Electrical Characteristics (Unless otherwise specified, Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT	
Current transfer ratio	I _C / I _F	I _F = 5 mA, V _{CE} = 5 V	50	-	600	%	
		Rank GB	100	-	600	70	
Saturated current transfer ratio	I _C / I _{F (sat)}	$I_{F} = 1 \text{ mA}, V_{CE} = 0.4 \text{ V}$	-	60	-	%	
		Rank GB	30	-	-	70	
	V _{CE (sat)}	I _C = 2.4 mA, I _F = 8 mA	-	-	0.3		
Collector-emitter saturation voltage		I _C = 0.2 mA, I _F = 1 mA	-	0.2	-	V	
		Rank GB	-	-	0.3		
OFF-state collector current	I _{C (off)}	$V_{F} = 0.7 \text{ V}, V_{CE} = 48 \text{ V}$	-	-	10	μΑ	

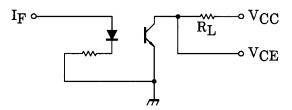
Isolation Characteristics (Unless otherwise specified, Ta = 25°C)

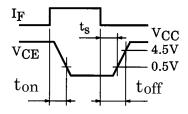
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Total capacitance (input to output)	CS	V _S = 0 V, f = 1 MHz	-	0.8	-	pF
Isolation resistance	R _S	V _S = 500 V, R.H.≤60%	1×10 ¹²	10 ¹⁴	-	Ω
		AC, 1 minute	3750	-	-	Vrms
Isolation voltage	BVS	AC , 1 second, in OIL -	-	10000	-	VIIIS
		DC, 1 minute, in OIL	-	10000	-	Vdc

Switching Characteristics (Unless otherwise specified, Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Rise time	tr	$V_{CC} = 10 \text{ V}, \text{ I}_{C} = 2 \text{ mA}$ $R_{L} = 100\Omega$	-	2	-	μs
Fall time	t _f		-	3	-	
Turn-on time	t _{on}		-	3	-	
Turn-off time	t _{off}		-	3	-	
Turn-on time	t _{on}		-	0.5	-	
Storage time	ts	$R_L = 1.9 k\Omega$ (Fig.1) V _{CC} = 5 V, I _F = 16 mA	-	25	-	μs
Turn-off time	t _{off}		-	40	-	

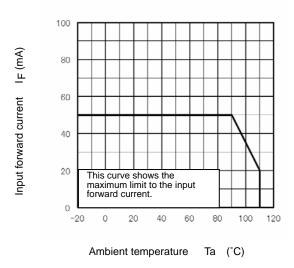
(Fig.1) Switching Time Test Circuit



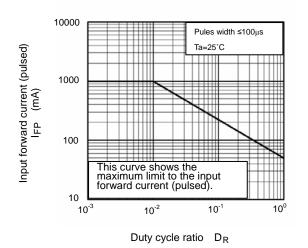


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IFP-DR





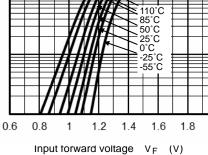


100

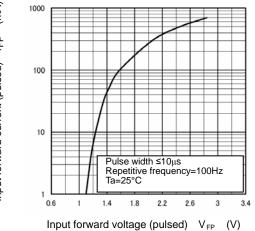
(MM)

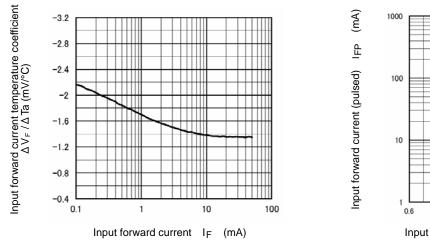
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Collector power dissipation



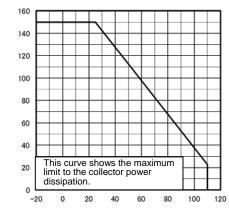
IFP - VFP





Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted





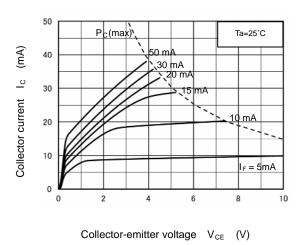
Ambient temperature Ta (°C)



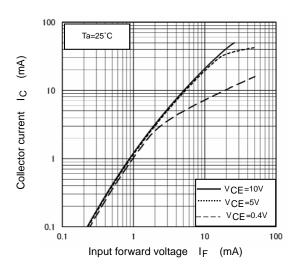
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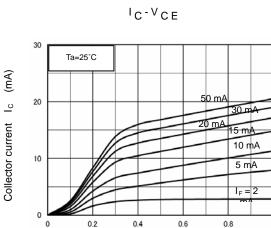
IC-VCE





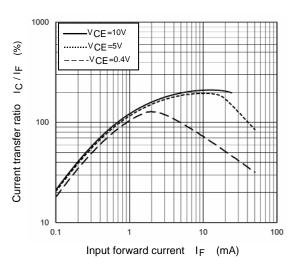




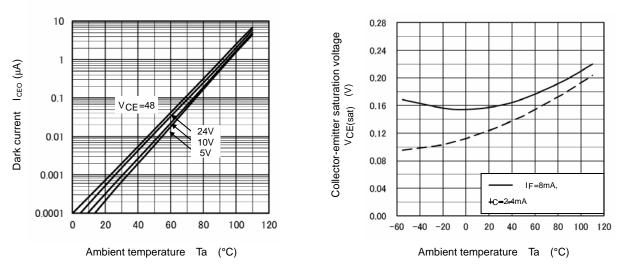


Collector-emitter voltage V_{CE} (V)

IC/IF -IF



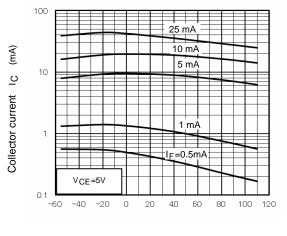
V_{CE(sat)} - Ta



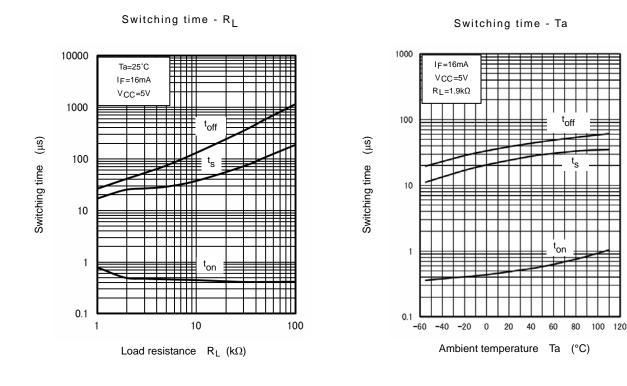
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted

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Ambient temperature Ta (°C)



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

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Soldering and Storage

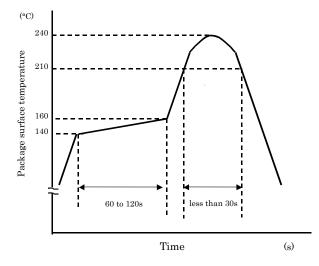
1. Soldering

1.1 Soldering

When using a soldering iron or medium infrared ray/hot air reflow, avoid a rise in device temperature as much as possible by observing the following conditions.

1) Using solder reflow

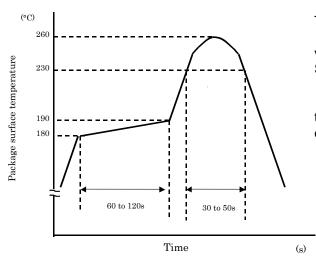
•Temperature profile example of lead (Pb) solder



This profile is based on the device's maximum heat resistance guaranteed value.

Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

•Temperature profile example of using lead (Pb)-free solder



This profile is based on the device's maximum heat resistance guaranteed value.

Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.

2) Using solder flow (for lead (Pb) solder, or lead (Pb)-free solder)

• Please preheat it at 150°C between 60 and 120 seconds.

· Complete soldering within 10 seconds below 260°C. Each pin may be heated at most once.

3) Using a soldering iron

Complete soldering within 10 seconds below 260°C, or within 3 seconds at 350°C. Each pin may be heated at most once.

2. Storage

- 1) Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- 2) Follow the precautions printed on the packing label of the device for transportation and storage.

3) Keep the storage location temperature and humidity within a range of 5°C to 35°C and 45% to 75%, respectively.

- 4) Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- 5) Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- 6) When restoring devices after removal from their packing, use anti-static containers.
- 7) Do not allow loads to be applied directly to devices while they are in storage.
- 8) If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

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